TOSHIBA Transistor Silicon PNP · NPN Epitaxial Type (PCT process) (Bias Resistor built-in Transistor)

## **RN49A1**

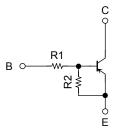
# Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications

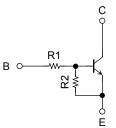
- Two devices are incorporated into an Ultra-Super-Mini (6 pin) package.
- Incorporating a bias resistor into a transistor reduces parts count.
   Reducing the parts count enable the manufacture of ever more compact equipment and save assembly cost.

#### **Equivalent Circuit and Bias Resistor Values**

Q1

Q2





Q1

R1: 2.2 k $\Omega$ , R2: 47 k $\Omega$ 

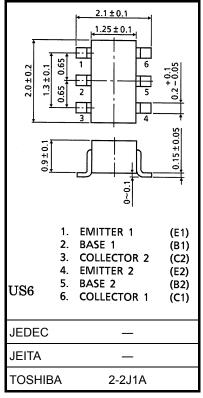
Q2

R1: 22 k $\Omega$ , R2: 47 k $\Omega$ 

Q1:RN2105F equivalent

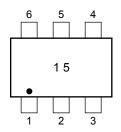
Q2:RN1108F equivalent

#### Unit: mm

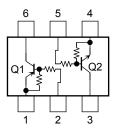


Weight: 0.006g (typ.)

#### Marking



#### **Equivalent Circuit (top view)**



#### Absolute Maximum Ratings (Ta = 25°C) (Q1)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	IC	-100	mA

#### Absolute Maximum Ratings (Ta = 25°C) (Q2)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	50	V
Collector-emitter voltage	V <sub>CEO</sub>	50	V
Emitter-base voltage	V <sub>EBO</sub>	7	V
Collector current	IC	100	mA

#### Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

Characteristics	Symbol	Rating	Unit
Collector power dissipation	P <sub>C</sub> (Note 1)	200	mW
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	-55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

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Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating

## Electrical Characteristics (Ta = 25°C) (Q1)

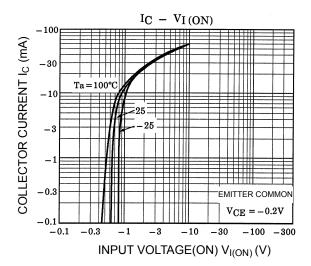
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -50 \text{ V}, I_E = 0$	_	_	-100	nA
	I <sub>CEO</sub>	$V_{CE} = -50 \text{ V}, I_B = 0$	_	_	-500	ш
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -5 \text{ V}, I_{C} = 0$	-0.078	_	-0.145	mA
DC current gain	h <sub>FE</sub>	$V_{CE} = -5 \text{ V}, I_{C} = -10 \text{ mA}$	80	_	_	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	$I_C = -5 \text{ mA}, I_B = -0.25 \text{ mA}$	_	-0.1	-0.3	٧
Input voltage (ON)	V <sub>I (ON)</sub>	$V_{CE} = -0.2 \text{ V}, I_{C} = -5 \text{ mA}$	-0.6	_	-1.1	V
Input voltage (OFF)	V <sub>I (OFF)</sub>	$V_{CE} = -5 \text{ V}, I_{C} = -0.1 \text{ mA}$	-0.5	_	-0.8	V
Transition frequency	f <sub>T</sub>	$V_{CE} = -10 \text{ V}, I_{C} = -5 \text{ mA}$	_	200	_	MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	3	_	pF
Input resistance	R1	_	1.54	2.2	2.86	kΩ
Resistance ratio	R1/R2	_	0.0421	0.0468	0.0515	_

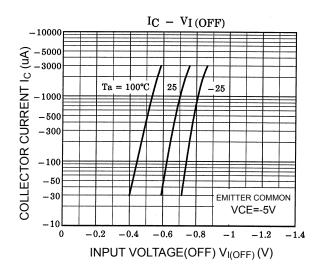
## Electrical Characteristics (Ta = 25°C) (Q2)

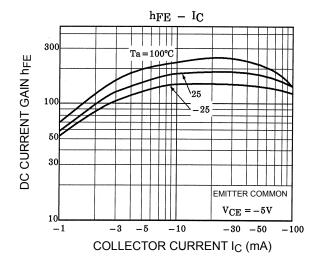
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = 50 \text{ V}, I_{E} = 0$	_	_	100	nA
Collector cut-on current	I <sub>CEO</sub>	$V_{CE} = 50 \text{ V}, I_{B} = 0$	_	_	500	
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = 7 \text{ V, } I_{C} = 0$	0.078	_	0.145	mA
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 10 mA	80	_	_	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	$I_C = 5 \text{ mA}, I_B = 0.25 \text{ mA}$	_	0.1	0.3	V
Input voltage (ON)	V <sub>I (ON)</sub>	$V_{CE} = 0.2 \text{ V}, I_{C} = 5 \text{ mA}$	1.0	_	2.6	V
Input voltage (OFF)	V <sub>I (OFF)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.1 mA	0.6	_	1.16	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 5 mA	_	250	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	3	_	pF
Input resistance	R1	_	1.54	22	2.86	kΩ
Resistance ratio	R1/R2	_	0.421	0. 468	0. 515	_

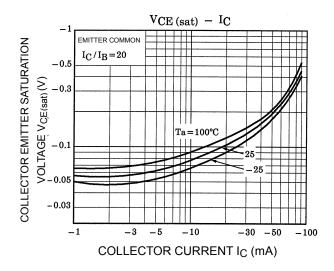
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Q1

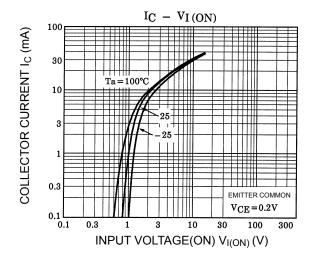


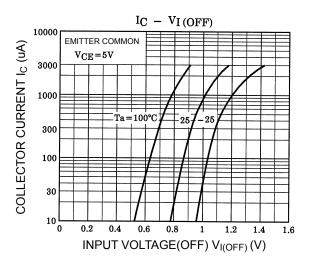


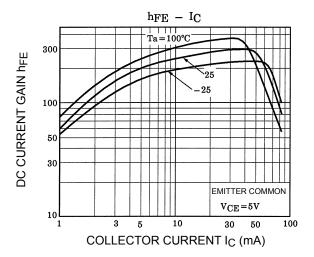


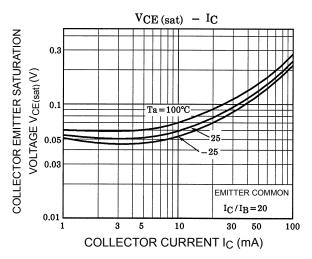


Q2



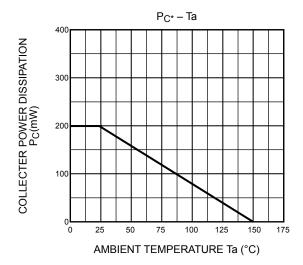






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## Q1,Q2 COMMON



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